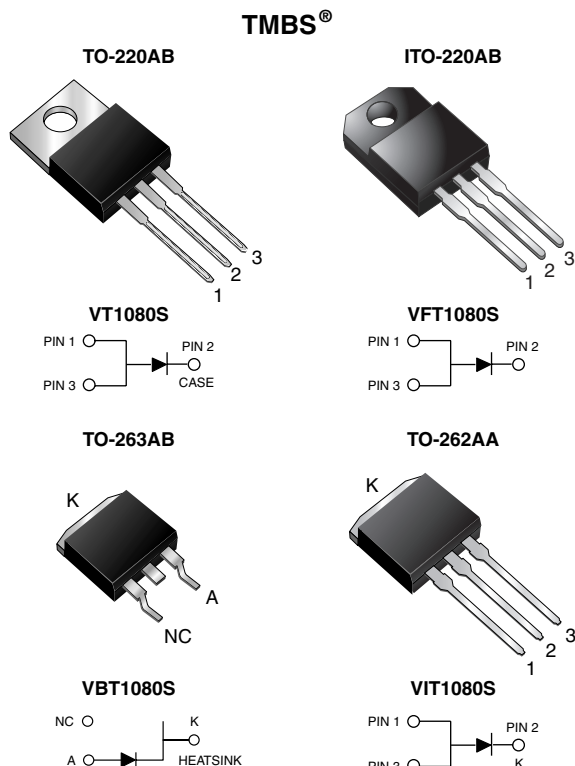


## Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.52 \text{ V}$  at  $I_F = 5 \text{ A}$



### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### PRIMARY CHARACTERISTICS

|                               |        |
|-------------------------------|--------|
| $I_{F(AV)}$                   | 10 A   |
| $V_{RRM}$                     | 80 V   |
| $I_{FSM}$                     | 100 A  |
| $V_F$ at $I_F = 10 \text{ A}$ | 0.60 V |
| $T_J \text{ max.}$            | 150 °C |

### MAXIMUM RATINGS ( $T_A = 25 \text{ °C}$ unless otherwise noted)

| PARAMETER                                                                                                         | SYMBOL         | VT1080S       | VFT1080S | VBT1080S | VIT1080S | UNIT |
|-------------------------------------------------------------------------------------------------------------------|----------------|---------------|----------|----------|----------|------|
| Maximum repetitive peak reverse voltage                                                                           | $V_{RRM}$      | 80            |          |          |          | V    |
| Maximum average forward rectified current (fig. 1)                                                                | $I_{F(AV)}$    | 10            |          |          |          | A    |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load                                | $I_{FSM}$      | 100           |          |          |          | A    |
| Non-repetitive avalanche energy at $T_J = 25 \text{ °C}$ , $L = 60 \text{ mH}$                                    | $E_{AS}$       | 110           |          |          |          | mJ   |
| Peak repetitive reverse current at $t_p = 2 \text{ } \mu\text{s}$ , 1 kHz, $T_J = 38 \text{ °C} \pm 2 \text{ °C}$ | $I_{RRM}$      | 1.0           |          |          |          | A    |
| Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1 \text{ min}$                                  | $V_{AC}$       | 1500          |          |          |          | V    |
| Operating junction and storage temperature range                                                                  | $T_J, T_{STG}$ | - 55 to + 150 |          |          |          | °C   |

## VT1080S, VFT1080S, VBT1080S, VIT1080S

Vishay General Semiconductor

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

| PARAMETER                     | TEST CONDITIONS        |                         | SYMBOL                        | TYP.         | MAX. | UNIT |
|-------------------------------|------------------------|-------------------------|-------------------------------|--------------|------|------|
| Breakdown voltage             | I <sub>R</sub> = 10 mA | T <sub>A</sub> = 25 °C  | V <sub>BR</sub>               | 80 (minimum) | -    | V    |
| Instantaneous forward voltage | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | 0.57         | -    | V    |
|                               | I <sub>F</sub> = 10 A  |                         |                               | 0.67         | 0.81 |      |
|                               | I <sub>F</sub> = 5 A   | T <sub>A</sub> = 125 °C |                               | 0.52         | -    |      |
|                               | I <sub>F</sub> = 10 A  |                         |                               | 0.60         | 0.70 |      |
|                               |                        |                         |                               |              |      |      |
| Reverse current               | V <sub>R</sub> = 80 V  | T <sub>A</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup> | 20           | 600  | μA   |
|                               |                        | T <sub>A</sub> = 125 °C |                               | 10           | 20   | mA   |

**Notes**(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle(2) Pulse test: Pulse width  $\leq 40\text{ ms}$ **THERMAL CHARACTERISTICS** ( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

| PARAMETER                  | SYMBOL          | VT1080S | VFT1080S | VBT1080S | VIT1080S | UNIT                 |
|----------------------------|-----------------|---------|----------|----------|----------|----------------------|
| Typical thermal resistance | $R_{\theta JC}$ | 2.2     | 5.5      | 2.2      | 2.2      | $^{\circ}\text{C/W}$ |

**ORDERING INFORMATION** (Example)

| PACKAGE   | PREFERRED P/N  | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |
|-----------|----------------|-----------------|--------------|---------------|---------------|
| TO-220AB  | VT1080S-E3/4W  | 1.88            | 4W           | 50/tube       | Tube          |
| ITO-220AB | VFT1080S-E3/4W | 1.73            | 4W           | 50/tube       | Tube          |
| TO-263AB  | VBT1080S-E3/4W | 1.36            | 4W           | 50/tube       | Tube          |
| TO-263AB  | VBT1080S-E3/8W | 1.36            | 8W           | 800/reel      | Tape and reel |
| TO-262AA  | VIT1080S-E3/4W | 1.43            | 4W           | 50/tube       | Tube          |

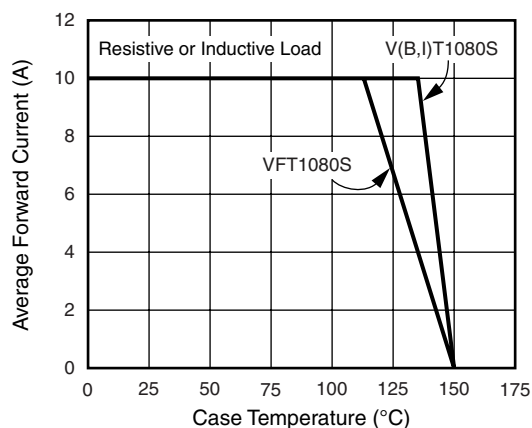
**RATINGS AND CHARACTERISTICS CURVES**( $T_A = 25\text{ }^{\circ}\text{C}$  unless otherwise noted)

Fig. 1 - Maximum Forward Current Derating Curve

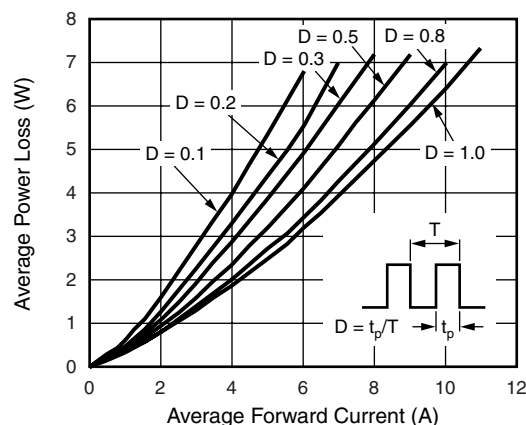


Fig. 2 - Forward Power Loss Characteristics

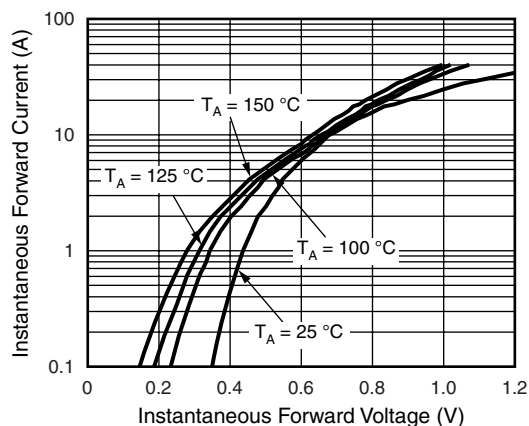


Fig. 3 - Typical Instantaneous Forward Characteristics

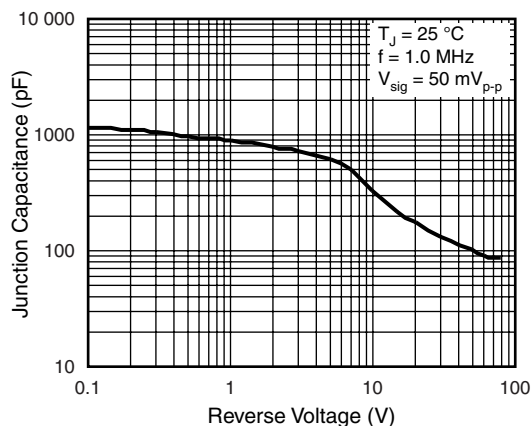


Fig. 5 - Typical Junction Capacitance

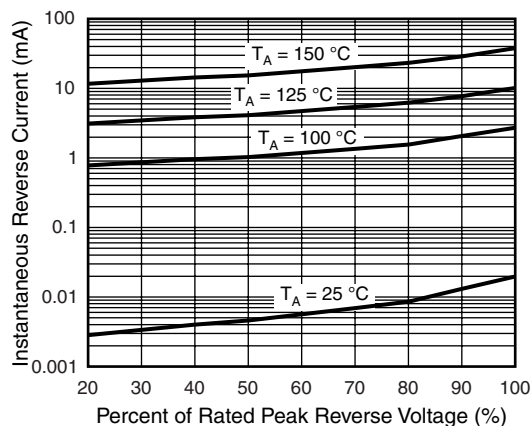


Fig. 4 - Typical Reverse Characteristics

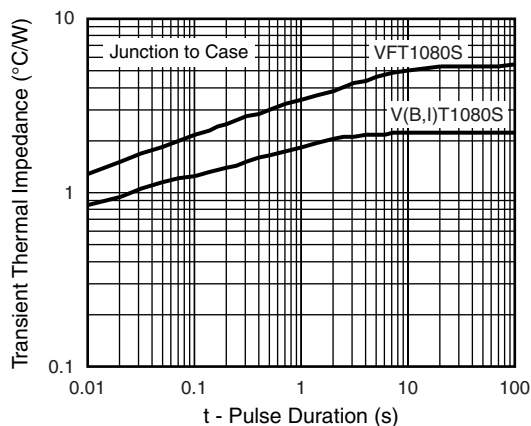


Fig. 6 - Typical Transient Thermal Impedance

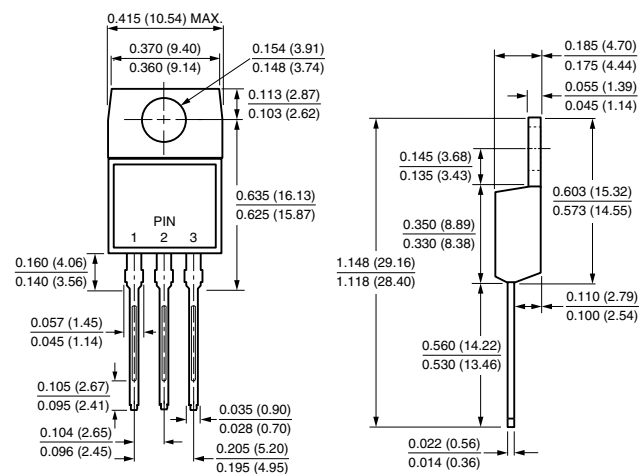
## VT1080S, VFT1080S, VBT1080S, VIT1080S

Vishay General Semiconductor

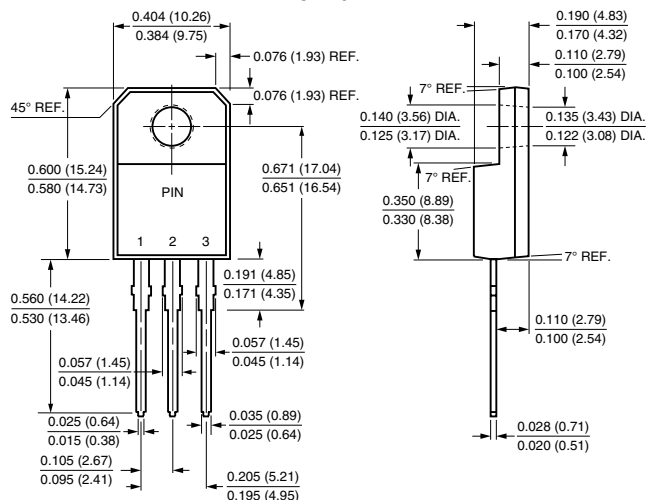


## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

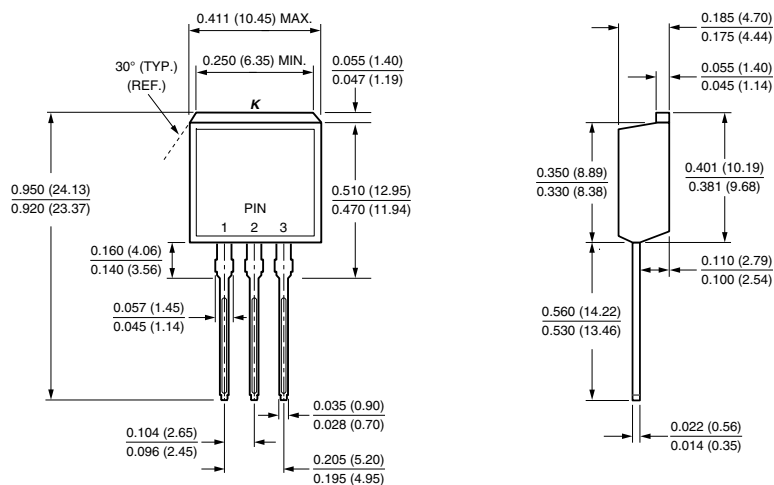
TO-220AB



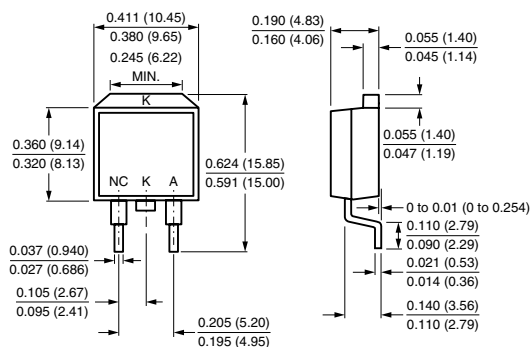
ITO-220AB



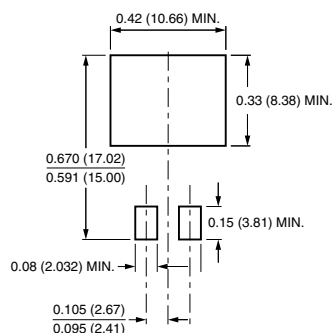
TO-262AA



TO-263AB



Mounting Pad Layout





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- Консультации по применению компонента;
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- Техническая поддержка проекта;
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